SK 70 KQ

SEMITOP® 1

Antiparallel Thyristor Module

SK 70 KQ

Preliminary Data

Features

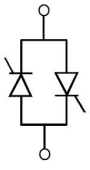
- Compact Design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passived thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

Typical Applications*

- Soft starters
- Light control (studios, theaters...)
- Temperature control

V_{RSM} V	V_{RRM}, V_{DRM} V	I_{RMS} = 72 A A (full conduction) (T_s = 85 °C)
900	800	SK 70 KQ 08
1300	1200	SK 70 KQ 12
1700	1600	SK 70 KQ 16

Symbol	Conditions	Values	Units
I_{RMS}	W1C ; sin. 180° ; T_s = 100°C	50	A
	W1C ; sin. 180° ; T_s = 85°C	72	A
I_{TSM}	T_{vj} = 25 °C ; 10 ms	1000	A
	T_{vj} = 125 °C ; 10 ms	900	A
i²t	T_{vj} = 25 °C ; 8,3...10 ms	5000	A²s
	T_{vj} = 125 °C ; 8,3...10 ms	4000	A²s
V_T	T_{vj} = 25 °C, I_T = 120 A	max. 1,8	V
$V_{T(TO)}$	T_{vj} = 125 °C	max. 1	V
r_T	T_{vj} = 125 °C	max. 6	mΩ
I_{DD};I_{RD}	T_{vj} = 25 °C, V_{RD}=V_{RRM}	max. 0,5	mA
	T_{vj} = 125 °C, V_{RD}=V_{RRM}	max. 15	mA
t_{gd}	T_{vj} = 25 °C, I_G = 1 A; di_G/dt= 1 A/µs	1	µs
t_{gr}	V_D = 0,67 *V_{DRM}	2	µs
$(dv/dt)_{cr}$	T_{vj} = 125 °C	1000	V/µs
$(di/dt)_{cr}$	T_{vj} = 125 °C; f= 50...60 Hz	50	A/µs
t_q	T_{vj} = 125 °C; typ.	80	µs
I_H	T_{vj} = 25 °C; typ. / max.	100 / 200	mA
I_L	T_{vj} = 25 °C; R_G = 33 Ω; typ. / max.	200 / 400	mA
V_{GT}	T_{vj} = 25 °C; d.c.	min. 2	V
I_{GT}	T_{vj} = 25 °C; d.c.	min. 100	mA
V_{GD}	T_{vj} = 125 °C; d.c.	max. 0,25	V
I_{GD}	T_{vj} = 125 °C; d.c.	max. 5	mA
$R_{th(j-s)}$	cont. per thyristor	0,8	K/W
	sin 180° per thyristor	0,84	K/W
$R_{th(j-s)}$	cont. per W1C	0,4	K/W
	sin 180° per W1C	0,42	K/W
T_{vj}		-40 ... +125	°C
T_{stg}		-40 ... +125	°C
T_{solder}	terminals, 10s	260	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 / 2500	V~
M_s	Mounting torque to heatsink	1,5	Nm
M_t			Nm
a			m/s²
m		13	g
Case	SEMITOP® 1	T 1	



KQ

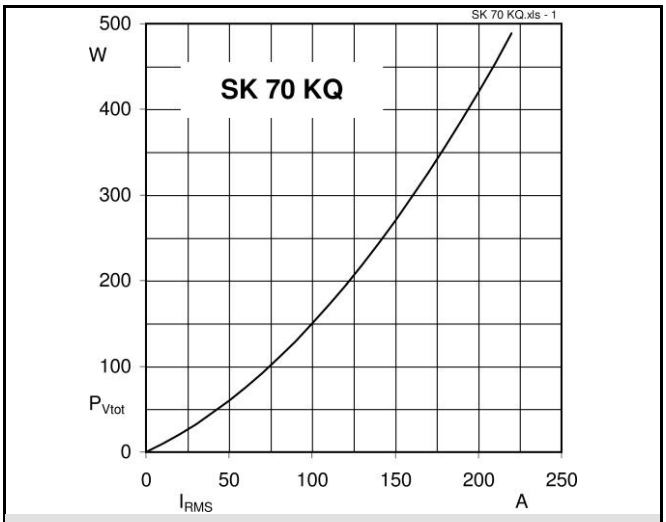


Fig. 1 Power dissipation per module vs. r.m.s. current

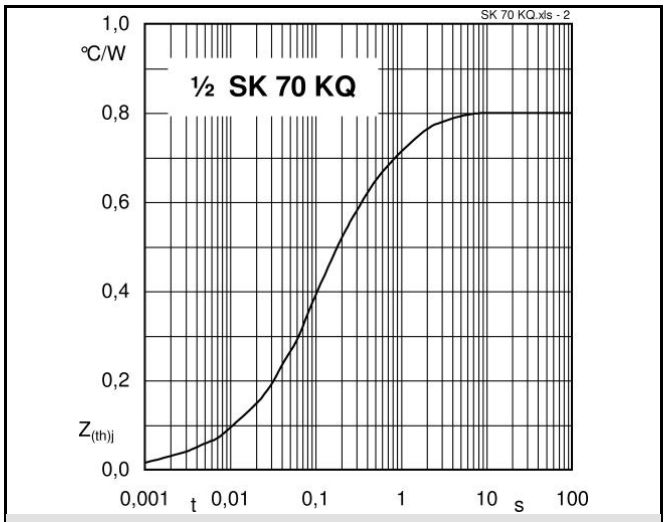


Fig. 2 Transient thermal impedance vs. time

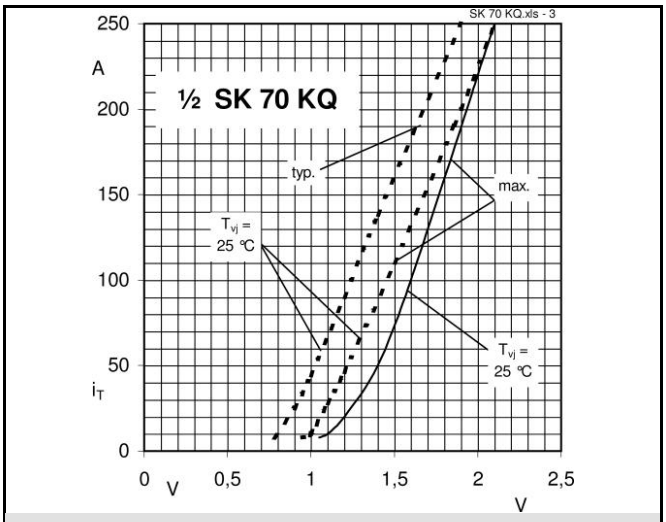


Fig. 3 On-state characteristics

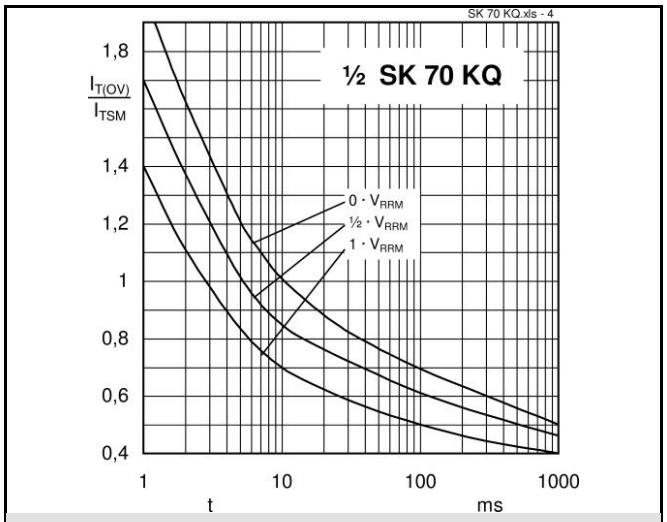


Fig. 4 Surge overload current vs. time

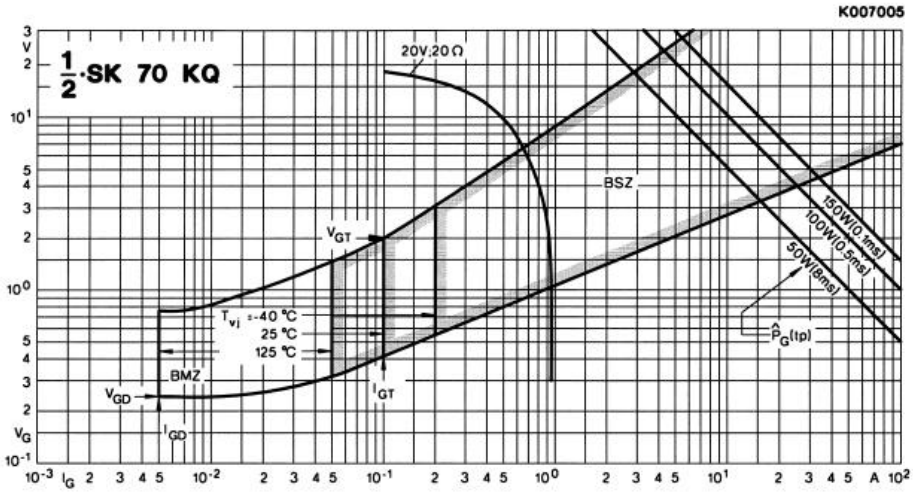
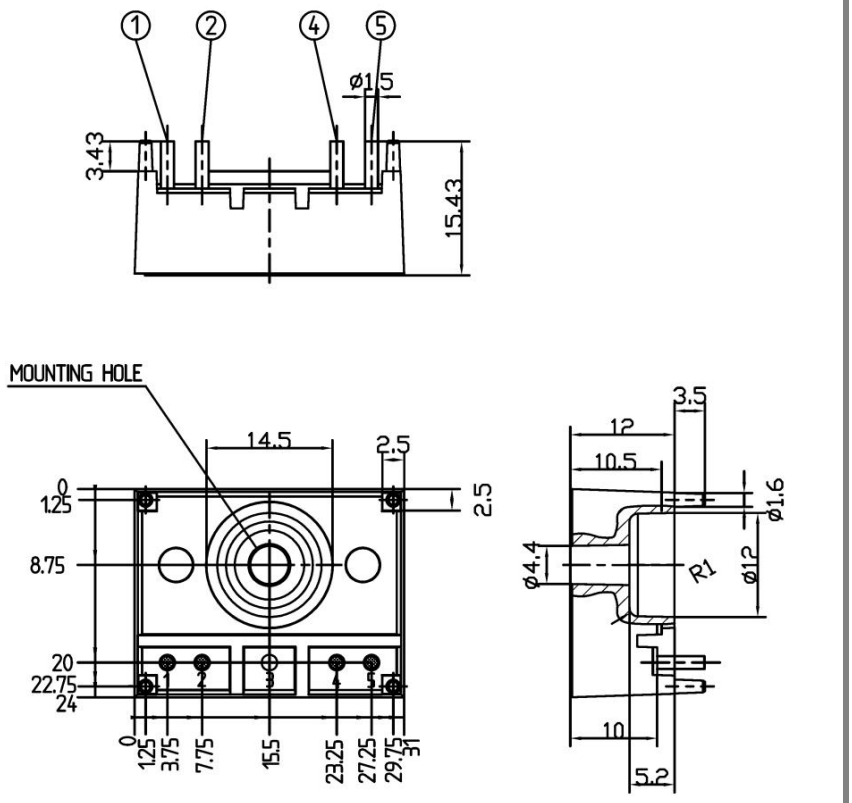
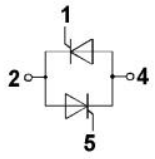


Fig. 5 Gate trigger characteristics

Dimensions in mm



Case T 1 (Suggested hole diameter in the PCB for solder pins and mounting pins: 2mm)



Case T1 KQ

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.